

SNOSBE5G - MARCH 2000 - REVISED APRIL 2013

LM2931-N Series Low Dropout Regulators

Check for Samples: LM2931-N

FEATURES

- **Very Low Quiescent Current**
- Output Current in Excess of 100 mA
- Input-output Differential Less than 0.6V
- **Reverse Battery Protection**
- 60V Load Dump Protection
- -50V Reverse Transient Protection
- **Short Circuit Protection**
- Internal Thermal Overload Protection
- **Mirror-image Insertion Protection**
- Available in TO-220, TO-92, TO-263, or SOIC-8 Packages
- Available as Adjustable with TTL Compatible Switch

DESCRIPTION

The LM2931-N positive voltage regulator features a very low quiescent current of 1mA or less when supplying 10mA loads. This unique characteristic and the extremely low input-output differential required for proper regulation (0.2V for output currents of 10mA) make the LM2931-N the ideal regulator for standby power systems. Applications include memory standby circuits, CMOS and other low power processor power supplies as well as systems demanding as much as 100mA of output current.

Designed originally for automotive applications, the LM2931-N and all regulated circuitry are protected from reverse battery installations or 2 battery jumps. During line transients, such as a load dump (60V) when the input voltage to the regulator can specified momentarily exceed the maximum operating voltage, the regulator will automatically shut down to protect both internal circuits and the load. The LM2931-N cannot be harmed by temporary mirror-image insertion. Familiar regulator features such as short circuit and thermal overload protection are also provided.

The LM2931-N family includes a fixed 5V output (±3.8% tolerance for A grade) or an adjustable output with ON/OFF pin. Both versions are available in a TO-220 power package, DDPAK/TO-263 surface mount package, and an 8-lead SOIC package. The fixed output version is also available in the TO-92 plastic package.

Connection Diagrams

FIXED VOLTAGE OUTPUT

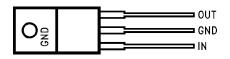


Figure 1. TO-220 3-Lead Power Package **Front View**

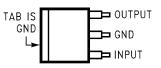


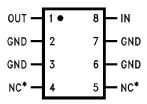
Figure 2. DDPAK/TO-263 Surface-Mount Package **Top View**



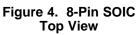


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*NC = Not internally connected. Must be electrically isolated from the rest of the circuit for the DSBGA package.



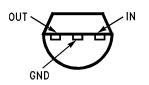


Figure 5. TO-92 Plastic Package Bottom View

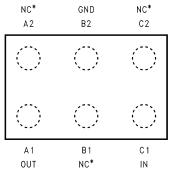


Figure 6. 6-Bump DSBGA Top View (Bump Side Down)

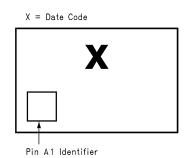
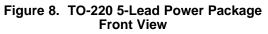


Figure 7. DSBGA Laser Mark

ADJUSTABLE OUTPUT VOLTAGE





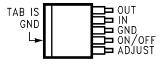
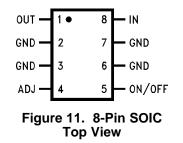




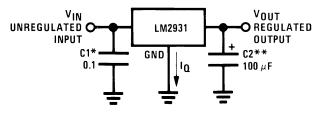


Figure 10. Side View





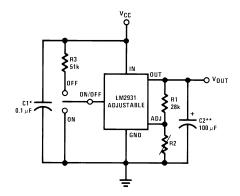
Typical Applications



*Required if regulator is located far from power supply filter.

**C2 must be at least 100 μF to maintain stability. May be increased without bound to maintain regulation during transients. Locate as close as possible to the regulator. This capacitor must be rated over the same operating temperature range as the regulator. The equivalent series resistance (ESR) of this capacitor is critical; see curve.

Figure 12. LM2931-N Fixed Output



 $V_{OUT} = \text{Reference Voltage} \times \frac{\text{R1} + \text{R2}}{\text{R1}}$

Note: Using 27k for R1 will automatically compensate for errors in V_{OUT} due to the input bias current of the ADJ pin (approximately 1 μ A).

Figure 13. LM2931-N Adjustable Output



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾⁽²⁾

Input Voltage	
Operating Range	26V
Overvoltage Protection	
LM2931A, LM2931C (Adjustable)	60V
LM2931-N	50V
Internal Power Dissipation	
(3) (4)	Internally Limited
Operating Ambient Temperature	
Range	−40°C to +85°C
Maximum Junction Temperature	125°C
Storage Temperature Range	−65°C to +150°C
Lead Temp. (Soldering, 10 seconds)	230°C
ESD Tolerance ⁽⁵⁾	2000V

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Electrical specifications do not apply when operating the device beyond its rated operating conditions.

(2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.

(3) See circuit in Typical Applications. To ensure constant junction temperature, low duty cycle pulse testing is used.

(4) The maximum power dissipation is a function of maximum junction temperature T_{Jmax}, total thermal resistance θ_{JA}, and ambient temperature T_A. The maximum allowable power dissipation at any ambient temperature is P_D = (T_{Jmax} - T_A)/θ_{JA}. If this dissipation is exceeded, the die temperature will rise above 150°C and the LM2931-N will go into thermal shutdown. For the LM2931-N in the TO-92 package, θ_{JA} is 195°C/W; in the SOIC-8 package, θ_{JA} is 160°C/W, and in the TO-220 package, θ_{JA} is 50°C/W; in the DDPAK/TO-263 package, θ_{JA} is 73°C/W; and the 6-Bump DSBGA package θ_{JA} is 290°C/W. If the TO-220 package is used with a heat sink, θ_{JA} is the sum of the package thermal resistance junction-to-case of 3°C/W and the thermal resistance added by the heat sink and thermal interface. If the TO-263 package is used, the thermal resistance can be reduced by increasing the P.C. board copper area thermally connected to the package: Using 0.5 square inches of copper area, θ_{JA} is 50°C/W; with 1 square inch of copper area, θ_{JA} is 37°C/W; and with 1.6 or more square inches of copper area, θ_{JA} is 32°C/W.

(5) Human body model, 100 pF discharged through 1.5 k Ω .

ELECTRICAL CHARACTERISTICS FOR FIXED 3.3V VERSION

 V_{IN} = 14V, I_O = 10mA, T_J = 25°C, C_2 = 100µF (unless otherwise specified) ⁽¹⁾

		LM29		
Parameter	Conditions	Тур	Limit (2)	Units
Output Voltage		3.3	3.465 3.135	V _{MAX} V _{MIN}
	$4V \le V_{IN} \le 26V$, $I_O = 100$ mA -40°C $\le T_J \le 125$ °C		3.630 2.970	V _{MAX} V _{MIN}
Line Regulation	$4V \le V_{IN} \le 26V$	4	33	mV _{MAX}
Load Regulation	$5mA \le I_O \le 100mA$	10	50	mV _{MAX}
Output Impedance	100mA _{DC} and 10mA _{rms} , 100Hz - 10kHz	200		mΩ
Quiescent Current	$I_0 \le 10$ mA, 4V $\le V_{IN} \le 26$ V	0.4	1.0	mA _{MAX}
	$-40^{\circ}C \le T_{J} \le 125^{\circ}C$			
	$I_{O} = 100 \text{mA}, V_{IN} = 14 \text{V}, T_{J} = 25^{\circ}\text{C}$	15		mA
Output Noise Voltage	10Hz -100kHz, C _{OUT} = 100µF	330		μV _{rms}
Long Term Stability		13		mV/1000 hr
Ripple Rejection	f _O = 120Hz	80		dB

(1) See circuit in Typical Applications. To ensure constant junction temperature, low duty cycle pulse testing is used.

(2) All limits are specified for $T_J = 25^{\circ}C$ (standard type face) or over the full operating junction temperature range of $-40^{\circ}C$ to $+125^{\circ}C$ (bold type face).



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ELECTRICAL CHARACTERISTICS FOR FIXED 3.3V VERSION (continued)

 V_{IN} = 14V, I_O = 10mA, T_J = 25°C, C_2 = 100µF (unless otherwise specified) ⁽¹⁾

Parameter		LM2		
	Conditions	Тур	Limit	Units
Dropout Voltage	I _O = 10mA I _O = 100mA	0.05 0.30	0.2 0.6	V _{MAX}
Maximum Operational Input Voltage		33	26	V _{MIN}
Maximum Line Transient	$R_L = 500\Omega, V_O \le 5.5V,$ T = 1ms, τ ≤ 100ms	70	50	V _{MIN}
Reverse Polarity Input Voltage, DC	$V_{O} \ge -0.3V$, $R_{L} = 500\Omega$	-30	-15	V _{MIN}
Reverse Polarity Input Voltage, Transient	$T = 1ms$, $\tau \le 100ms$, $R_L = 500\Omega$	-80	-50	V _{MIN}

ELECTRICAL CHARACTERISTICS FOR FIXED 5V VERSION

 V_{IN} = 14V, I_{O} = 10mA, T_{J} = 25°C, C2 = 100 μF (unless otherwise specified) $^{(1)}$

		LM29:	31A-5.0	LM293		
Parameter	Conditions	Тур	Limit	Тур	Limit	Units
Output Voltage		5	5.19 4.81	5	5.25 4.75	V _{MAX} V _{MIN}
	$6.0V \le V_{IN} \le 26V, I_O = 100mA$ -40°C $\le T_J \le 125$ °C		5.25 4.75		5.5 4.5	V _{MAX} V _{MIN}
Line Regulation	$9V \le V_{IN} \le 16V$ $6V \le V_{IN} \le 26V$	2 4	10 30	2 4	10 30	mV _{MAX}
Load Regulation	$5 \text{ mA} \le I_{O} \le 100 \text{mA}$	14	50	14	50	mV _{MAX}
Output Impedance	100mA _{DC} and 10mA _{rms} , 100Hz -10kHz	200		200		mΩ
Quiescent Current	$I_0 \le 10$ mA, $6V \le V_{IN} \le 26V$	0.4	1.0	0.4	1.0	mA _{MAX}
	−40°C ≤ T _J ≤ 125°C					
	$I_{O} = 100 \text{mA}, V_{IN} = 14 \text{V}, T_{J} = 25^{\circ}\text{C}$	15	30	15		mA _{MAX}
Output Noise Voltage	$10Hz - 100kHz, C_{OUT} = 100\mu F$	500		500		μV _{rms}
Long Term Stability		20		20		mV/1000 hr
Ripple Rejection	f _O = 120 Hz	80	55	80		dB _{MIN}
Dropout Voltage	$I_{O} = 10mA$ $I_{O} = 100mA$	0.05 0.3	0.2 0.6	0.05 0.3	0.2 0.6	V _{MAX}
Maximum Operational Input Voltage		33	26	33	26	V _{MIN}
Maximum Line Transient	$ \begin{array}{l} R_{L} = 500\Omega, V_{O} \leq 5.5V, \\ T = 1ms, T \leq 100ms \end{array} \end{array} $	70	60	70	50	V _{MIN}
Reverse Polarity Input Voltage, DC	$V_{O} \ge -0.3V, R_{L} = 500\Omega$	-30	-15	-30	-15	V _{MIN}
Reverse Polarity Input Voltage, Transient	$T = 1ms, \tau \le 100ms, R_L = 500\Omega$	-80	-50	-80	-50	V _{MIN}

(1) See circuit in Typical Applications. To ensure constant junction temperature, low duty cycle pulse testing is used.

(2) All limits are specified for $T_J = 25^{\circ}C$ (standard type face) or over the full operating junction temperature range of $-40^{\circ}C$ to $+125^{\circ}C$ (bold type face).

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ELECTRICAL CHARACTERISTICS FOR ADJUSTABLE VERSION

 V_{IN} = 14V, V_{OUT} = 3V, I_O = 10 mA, T_J = 25°C, R1 = 27k, C2 = 100 µF (unless otherwise specified) ⁽¹⁾

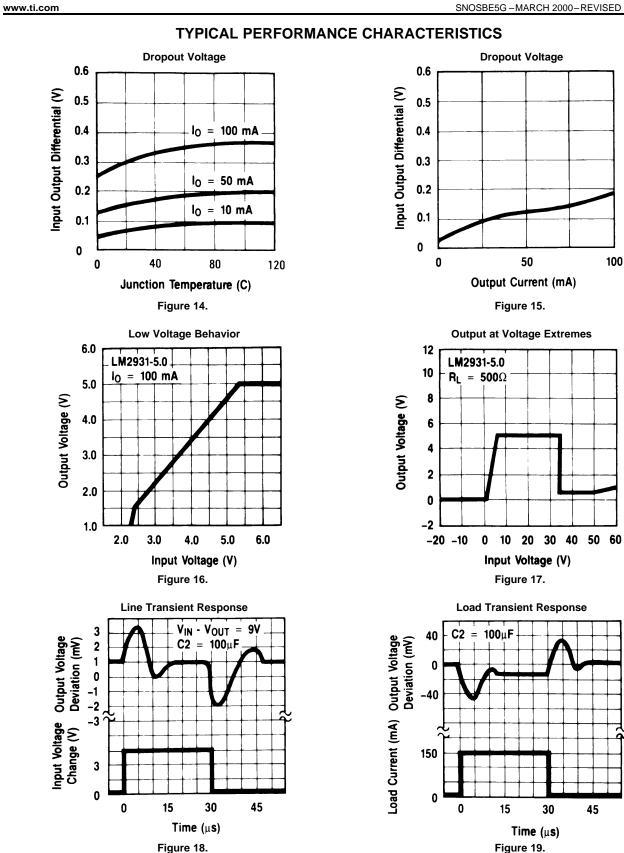
Parameter	Conditions	Тур	Limit	Units Limit
Reference Voltage		1.20	1.26	V _{MAX}
			1.14	V _{MIN}
	$I_0 \le 100 \text{ mA}, -40^{\circ}\text{C} \le T_j \le 125^{\circ}\text{C}, \text{ R1} = 27\text{k}$		1.32	V _{MAX}
	Measured from V _{OUT} to Adjust Pin		1.08	V _{MIN}
Output Voltage Range			24	V _{MAX}
			3	V _{MIN}
Line Regulation	$V_{OUT} + 0.6V \le V_{IN} \le 26V$	0.2	1.5	mV/V _{MAX}
Load Regulation	5 mA ≤ I _O ≤ 100 mA	0.3	1	% _{MAX}
Output Impedance	100 mA _{DC} and 10 mA _{rms} , 100 Hz–10 kHz	40		mΩ/V
Quiescent Current	I _O = 10 mA	0.4	1	mA _{MAX}
	I _O = 100 mA	15		mA
	During Shutdown $R_L = 500\Omega$	0.8	1	mA _{MAX}
Output Noise Voltage	10 Hz–100 kHz	100		μV _{rms} /V
Long Term Stability		0.4		%/1000 hr
Ripple Rejection	f _O = 120 Hz	0.02		%/V
Dropout Voltage	I _O ≤ 10 mA	0.05	0.2	V _{MAX}
	I _O = 100 mA	0.3	0.6	V _{MAX}
Maximum Operational Input				
Voltage		33	26	V _{MIN}
Maximum Line Transient	$I_0 = 10$ mA, Reference Voltage ≤ 1.5 V	70	60	V _{MIN}
	T = 1 ms, τ ≤ 100 ms			
Reverse Polarity Input	$V_{O} \ge -0.3V, R_{L} = 500\Omega$			
Voltage, DC		-30	-15	V _{MIN}
Reverse Polarity Input	$T = 1 \text{ ms}, \tau \le 100 \text{ ms}, R_L = 500\Omega$			
Voltage, Transient		-80	-50	V _{MIN}
On/Off Threshold Voltage	V _O =3V			
On		2.0	1.2	V _{MAX}
Off		2.2	3.25	V _{MIN}
On/Off Threshold Current		20	50	μΑ _{MAX}

(1) See circuit in Typical Applications. To ensure constant junction temperature, low duty cycle pulse testing is used.

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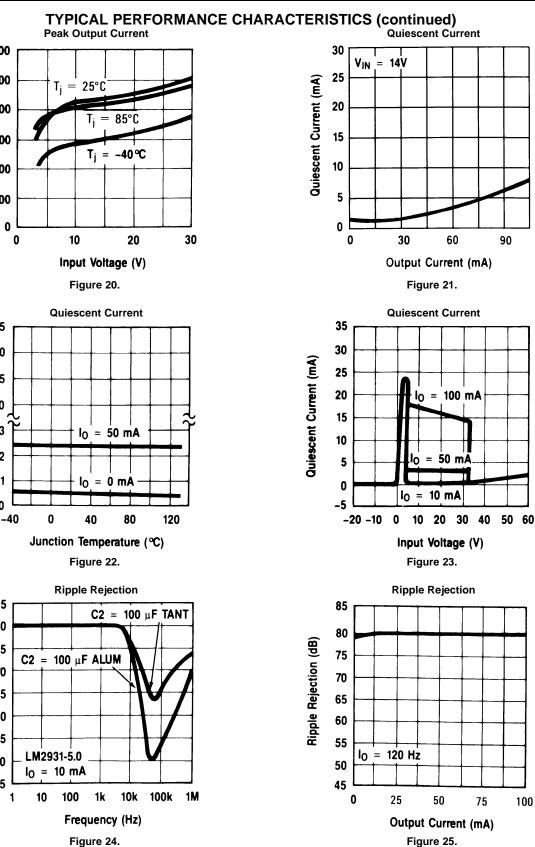
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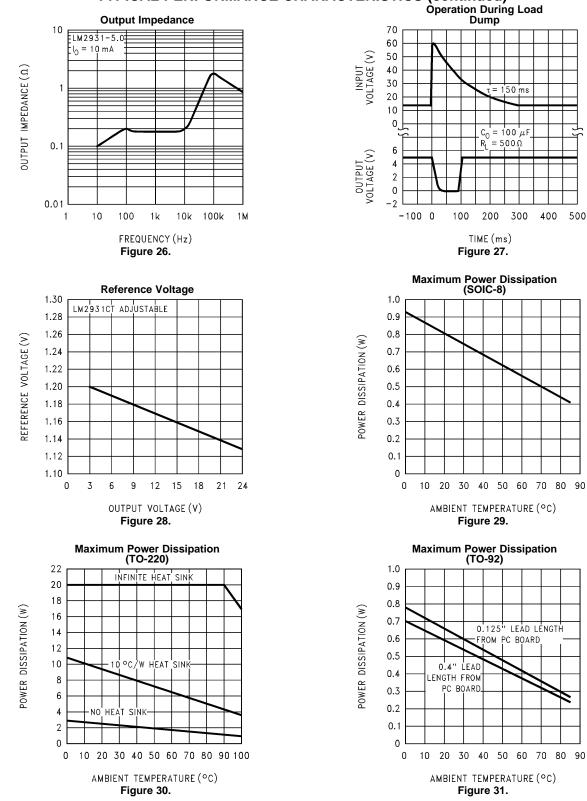
Ripple Rejection (dB)

Quiescent Current (mA)

Output Current (mA)



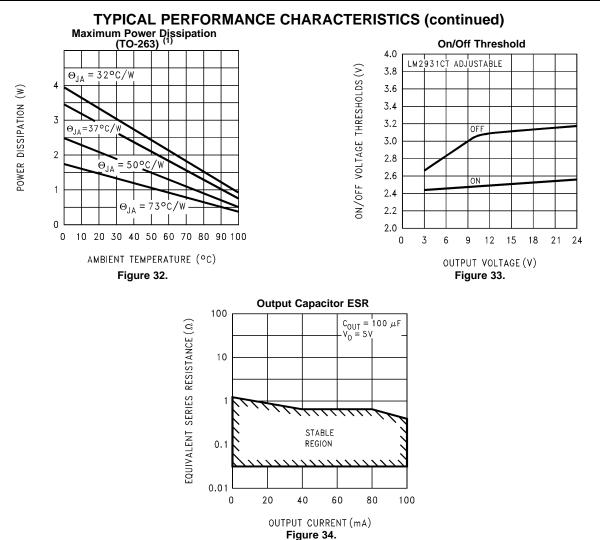




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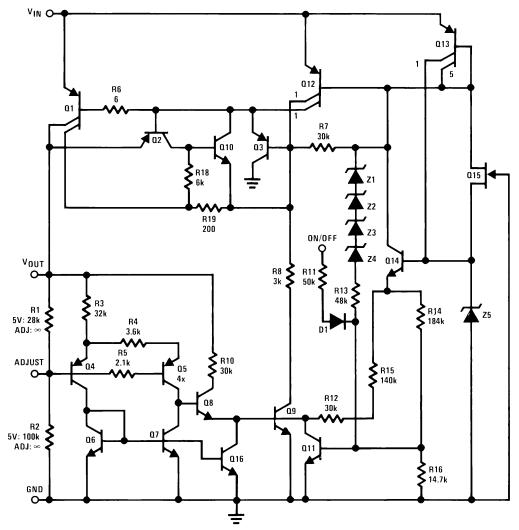
(1) The maximum power dissipation is a function of maximum junction temperature T_{Jmax}, total thermal resistance θ_{JA}, and ambient temperature T_A. The maximum allowable power dissipation at any ambient temperature is P_D = (T_{Jmax} - T_A)/θ_{JA}. If this dissipation is exceeded, the die temperature will rise above 150°C and the LM2931-N will go into thermal shutdown. For the LM2931-N in the TO-92 package, θ_{JA} is 155°C/W; in the SOIC-8 package, θ_{JA} is 160°C/W, and in the TO-220 package, θ_{JA} is 50°C/W; in the DDPAK/TO-263 package, θ_{JA} is 73°C/W; and in the 6-Bump DSBGA package θ_{JA} is 290°C/W. If the TO-220 package is used with a heat sink, θ_{JA} is the sum of the package thermal resistance junction-to-case of 3°C/W and the thermal resistance added by the heat sink and thermal interface. If the TO-263 package is used, the thermal resistance can be reduced by increasing the P.C. board copper area thermally connected to the package: Using 0.5 square inches of copper area, θ_{JA} is 50°C/W; with 1 square inch of copper area, θ_{JA} is 32°C/W; and with 1.6 or more square inches of copper area, θ_{JA} is 32°C/W.



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SCHEMATIC DIAGRAM





APPLICATION HINTS

One of the distinguishing factors of the LM2931-N series regulators is the requirement of an output capacitor for device stability. The value required varies greatly depending upon the application circuit and other factors. Thus some comments on the characteristics of both capacitors and the regulator are in order.

High frequency characteristics of electrolytic capacitors depend greatly on the type and even the manufacturer. As a result, a value of capacitance that works well with the LM2931-N for one brand or type may not necessary be sufficient with an electrolytic of different origin. Sometimes actual bench testing, as described later, will be the only means to determine the proper capacitor type and value. Experience has shown that, as a rule of thumb, the more expensive and higher quality electrolytics generally allow a smaller value for regulator stability. As an example, while a high-quality 100 μ F aluminum electrolytic covers all general application circuits, similar stability can be obtained with a tantalum electrolytic of only 47 μ F. This factor of two can generally be applied to any special application circuit also.

Another critical characteristic of electrolytics is their performance over temperature. While the LM2931-N is designed to operate to -40° C, the same is not always true with all electrolytics (hot is generally not a problem). The electrolyte in many aluminum types will freeze around -30° C, reducing their effective value to zero. Since the capacitance is needed for regulator stability, the natural result is oscillation (and lots of it) at the regulator output. For all application circuits where cold operation is necessary, the output capacitor must be rated to operate at the minimum temperature. By coincidence, worst-case stability for the LM2931-N also occurs at minimum temperatures. As a result, in applications where the regulator junction temperature will never be less than 25°C, the output capacitor can be reduced approximately by a factor of two over the value needed for the entire temperature range. To continue our example with the tantalum electrolytic, a value of only 22µF would probably thus suffice. For high-quality aluminum, 47µF would be adequate in such an application.

Another regulator characteristic that is noteworthy is that stability decreases with higher output currents. This sensible fact has important connotations. In many applications, the LM2931-N is operated at only a few milliamps of output current or less. In such a circuit, the output capacitor can be further reduced in value. As a rough estimation, a circuit that is required to deliver a maximum of 10mA of output current from the regulator would need an output capacitor of only half the value compared to the same regulator required to deliver the full output current of 100mA. If the example of the tantalum capacitor in the circuit rated at 25°C junction temperature and above were continued to include a maximum of 10mA of output current, then the 22 μ F output capacitor could be reduced to only 10 μ F.

In the case of the LM2931CT adjustable regulator, the minimum value of output capacitance is a function of the output voltage. As a general rule, the value decreases with higher output voltages, since internal loop gain is reduced.

At this point, the procedure for bench testing the minimum value of an output capacitor in a special application circuit should be clear. Since worst-case occurs at minimum operating temperatures and maximum operating currents, the entire circuit, including the electrolytic, should be cooled to the minimum temperature. The input voltage to the regulator should be maintained at 0.6V above the output to keep internal power dissipation and die heating to a minimum. Worst-case occurs just after input power is applied and before the die has had a chance to heat up. Once the minimum value of capacitance has been found for the brand and type of electrolytic in question, the value should be doubled for actual use to account for production variations both in the capacitor and the regulator. (All the values in this section and the remainder of the data sheet were determined in this fashion.)

LM2931-N DSBGA Light Sensitivity

When the LM2931-N DSBGA package is exposed to bright sunlight, normal office fluorescent light, and other LED's, it operates within the limits specified in the electrical characteristic table.



Definition of Terms

- **Dropout Voltage:** The input-output voltage differential at which the circuit ceases to regulate against further reduction in input voltage. Measured when the output voltage has dropped 100 mV from the nominal value obtained at 14V input, dropout voltage is dependent upon load current and junction temperature.
- Input Voltage: The DC voltage applied to the input terminals with respect to ground.
- **Input-Output Differential:** The voltage difference between the unregulated input voltage and the regulated output voltage for which the regulator will operate.
- Line Regulation: The change in output voltage for a change in the input voltage. The measurement is made under conditions of low dissipation or by using pulse techniques such that the average chip temperature is not significantly affected.
- Load Regulation: The change in output voltage for a change in load current at constant chip temperature.
- Long Term Stability: Output voltage stability under accelerated life-test conditions after 1000 hours with maximum rated voltage and junction temperature.
- **Output Noise Voltage:** The rms AC voltage at the output, with constant load and no input ripple, measured over a specified frequency range.
- **Quiescent Current:** That part of the positive input current that does not contribute to the positive load current. The regulator ground lead current.
- **Ripple Rejection:** The ratio of the peak-to-peak input ripple voltage to the peak-to-peak output ripple voltage at a specified frequency.
- Temperature Stability of V_o: The percentage change in output voltage for a thermal variation from room temperature to either temperature extreme.

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REVISION HISTORY

Cł	nanges from Revision F (April 2013) to Revision G P	age
•	Changed layout of National Data Sheet to TI format	. 13



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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM2931AM-5.0/NOPB	ACTIVE	SOIC	D	8	95	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	2931A M-5.0	Samples
LM2931AMX-5.0/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	2931A M-5.0	Samples
LM2931AS-5.0/NOPB	ACTIVE	DDPAK/ TO-263	КТТ	3	45	RoHS-Exempt & Green	SN	Level-3-245C-168 HR	-40 to 85	LM2931 AS5.0	Samples
LM2931ASX-5.0/NOPB	ACTIVE	DDPAK/ TO-263	КТТ	3	500	RoHS-Exempt & Green	SN	Level-3-245C-168 HR	-40 to 85	LM2931 AS5.0	Samples
LM2931AT-5.0/NOPB	ACTIVE	TO-220	NDE	3	45	RoHS & Green	SN	Level-1-NA-UNLIM	-40 to 85	LM2931 AT5.0	Samples
LM2931AZ-5.0/NOPB	OBSOLETE	E TO-92	LP	3		TBD	Call TI	Call TI	-40 to 85	LM293 1AZ-5	
LM2931CM/NOPB	ACTIVE	SOIC	D	8	95	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	LM29 31CM	Samples
LM2931CMX/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	LM29 31CM	Samples
LM2931CS/NOPB	ACTIVE	DDPAK/ TO-263	КТТ	5	45	RoHS-Exempt & Green	SN	Level-3-245C-168 HR	-40 to 85	LM2931CS	Samples
LM2931CT/NOPB	ACTIVE	TO-220	KC	5	45	RoHS & Green	SN	Level-1-NA-UNLIM	-40 to 85	LM2931CT	Samples
LM2931M-5.0/NOPB	ACTIVE	SOIC	D	8	95	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	2931 M-5.0	Samples
LM2931MX-5.0/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	2931 M-5.0	Samples
LM2931S-5.0/NOPB	ACTIVE	DDPAK/ TO-263	КТТ	3	45	RoHS-Exempt & Green	SN	Level-3-245C-168 HR	-40 to 85	LM2931S 5.0	Samples
LM2931T-5.0/NOPB	ACTIVE	TO-220	NDE	3	45	RoHS & Green	SN	Level-1-NA-UNLIM	-40 to 85	LM2931T 5.0	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect. NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.



⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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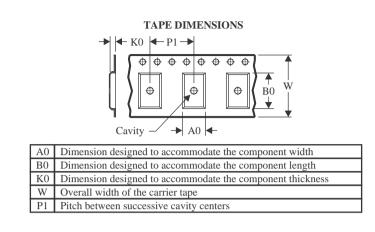


Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

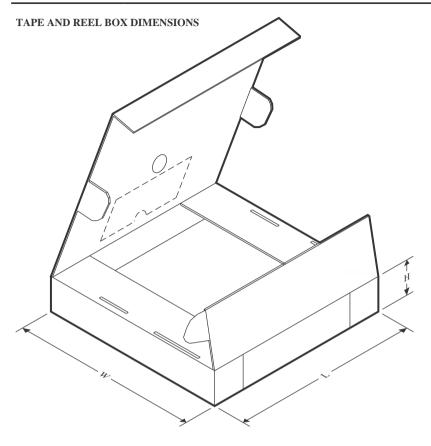


All dimensions are nominal												t.
Device	-	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM2931AMX-5.0/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM2931ASX-5.0/NOPB	DDPAK/ TO-263	КТТ	3	500	330.0	24.4	10.75	14.85	5.0	16.0	24.0	Q2
LM2931CMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM2931MX-5.0/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1



PACKAGE MATERIALS INFORMATION

11-May-2024



*All dimensions are nominal

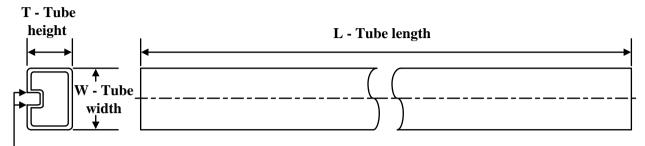
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM2931AMX-5.0/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM2931ASX-5.0/NOPB	DDPAK/TO-263	КТТ	3	500	356.0	356.0	45.0
LM2931CMX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM2931MX-5.0/NOPB	SOIC	D	8	2500	367.0	367.0	35.0

TEXAS INSTRUMENTS

www.ti.com

11-May-2024

TUBE



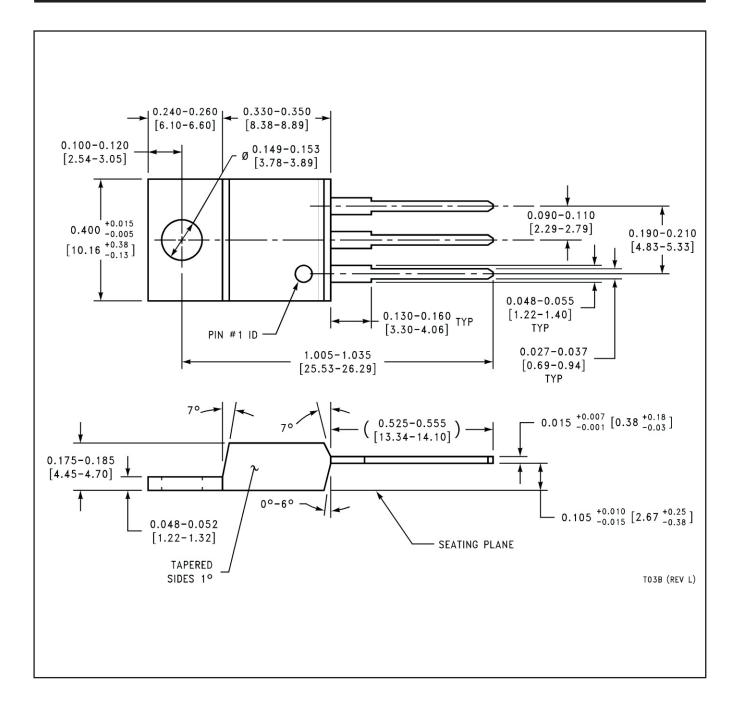
- B - Alignment groove width

*All dimensions are	e nominal
---------------------	-----------

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
LM2931AM-5.0/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM2931AS-5.0/NOPB	KTT	TO-263	3	45	502	25	8204.2	9.19
LM2931AT-5.0/NOPB	NDE	TO-220	3	45	502	33	6985	4.06
LM2931CM/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM2931CS/NOPB	KTT	TO-263	5	45	502	25	8204.2	9.19
LM2931CT/NOPB	КС	TO-220	5	45	502	33	6985	4.06
LM2931M-5.0/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM2931S-5.0/NOPB	KTT	TO-263	3	45	502	25	8204.2	9.19
LM2931T-5.0/NOPB	NDE	TO-220	3	45	502	33	6985	4.06

MECHANICAL DATA

NDE0003B





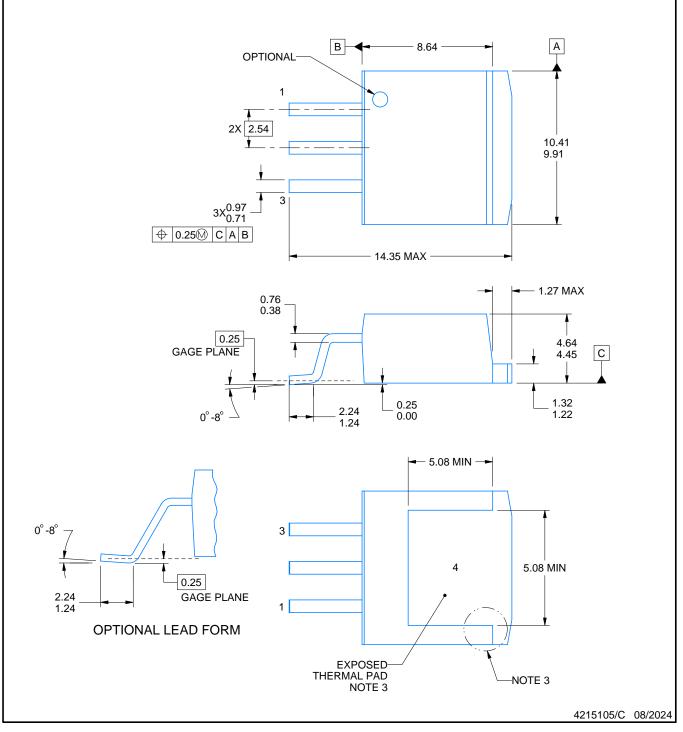
KTT0003B



PACKAGE OUTLINE

TO-263 - 4.83 mm max height

TRANSISTOR OUTLINE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.2. This drawing is subject to change without notice.

- Features may not exist and shape may vary per different assembly sites.
 Reference JEDEC registration TO-263, except minimum lead thickness and minimum exposed pad length.

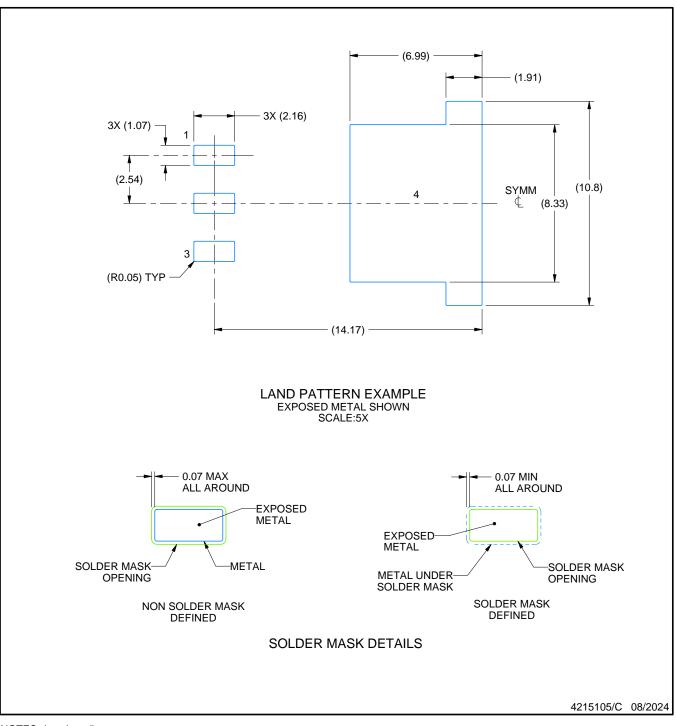


KTT0003B

EXAMPLE BOARD LAYOUT

TO-263 - 4.83 mm max height

TRANSISTOR OUTLINE



NOTES: (continued)

5. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002(www.ti.com/lit/slm002) and SLMA004 (www.ti.com/lit/slma004).

6. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.

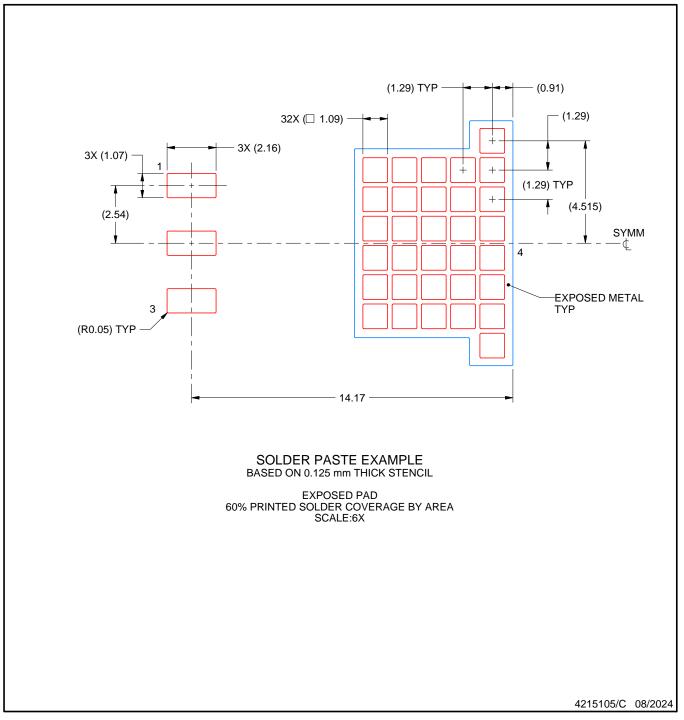


KTT0003B

EXAMPLE STENCIL DESIGN

TO-263 - 4.83 mm max height

TRANSISTOR OUTLINE



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations. 8. Board assembly site may have different recommendations for stencil design.



D0008A



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



D0008A

EXAMPLE BOARD LAYOUT

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



D0008A

EXAMPLE STENCIL DESIGN

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



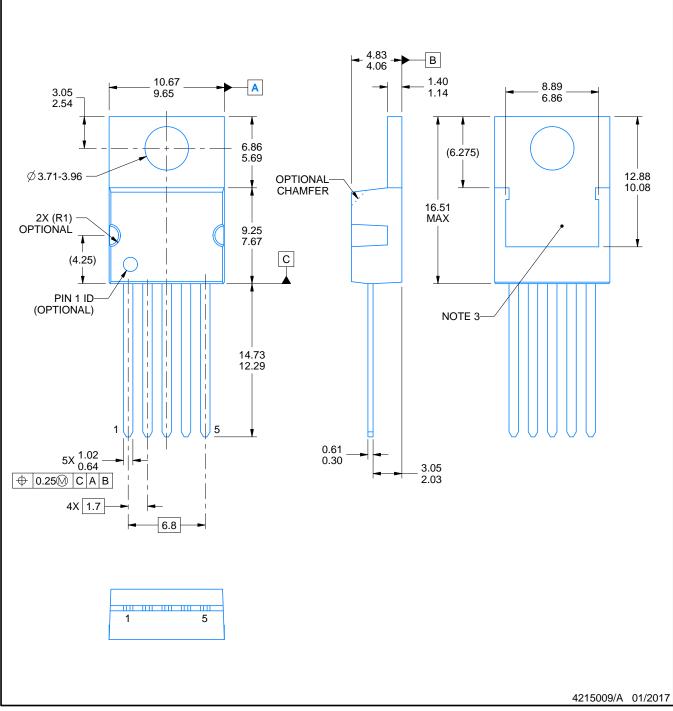
KC0005A



PACKAGE OUTLINE

TO-220 - 16.51 mm max height

TO-220



NOTES:

All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.

3. Shape may vary per different assembly sites.

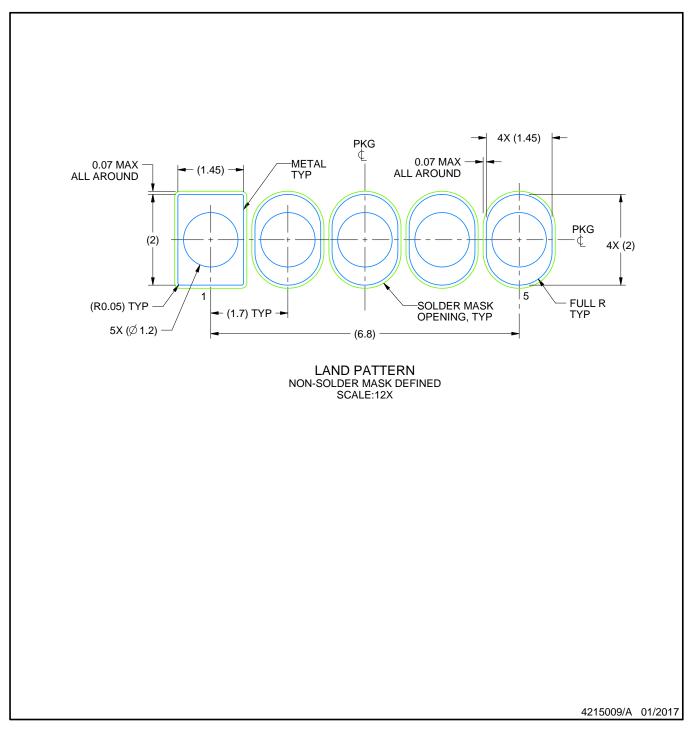


KC0005A

EXAMPLE BOARD LAYOUT

TO-220 - 16.51 mm max height

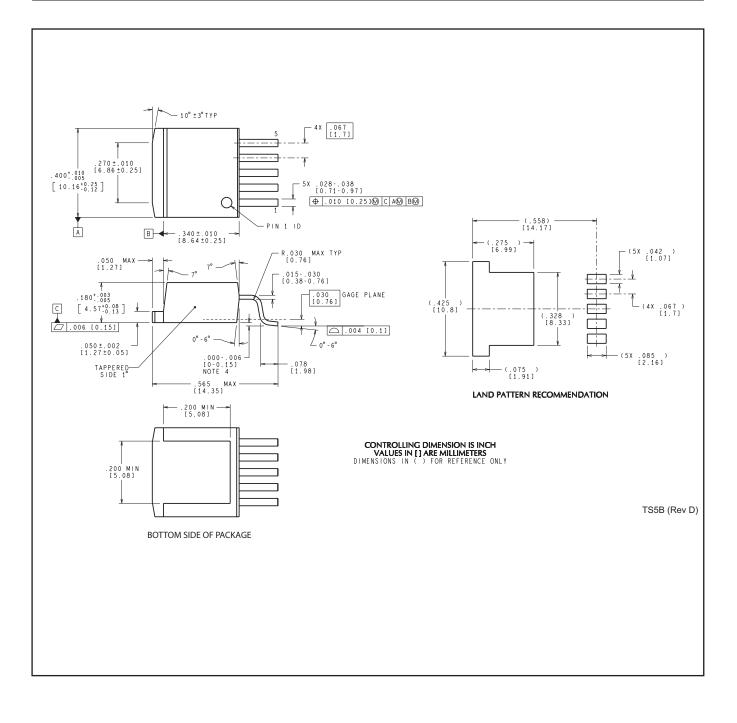
TO-220





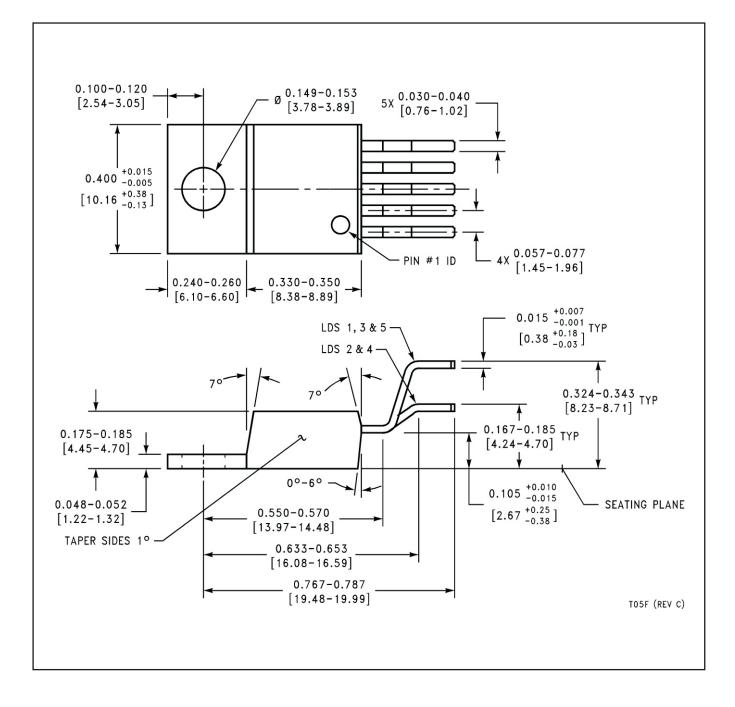
MECHANICAL DATA

KTT0005B





NEB0005F





GENERIC PACKAGE VIEW

TO-92 - 5.34 mm max height TRANSISTOR OUTLINE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



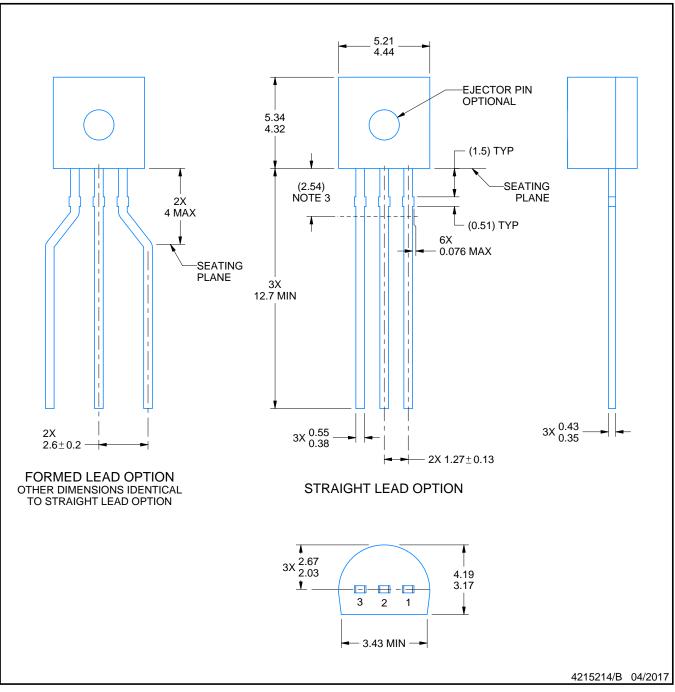
LP0003A



PACKAGE OUTLINE

TO-92 - 5.34 mm max height

TO-92



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- Lead dimensions are not controlled within this area.
 Reference JEDEC TO-226, variation AA.
- 5. Shipping method:

 - a. Straight lead option available in bulk pack only.b. Formed lead option available in tape and reel or ammo pack.
 - c. Specific products can be offered in limited combinations of shipping medium and lead options.
 - d. Consult product folder for more information on available options.

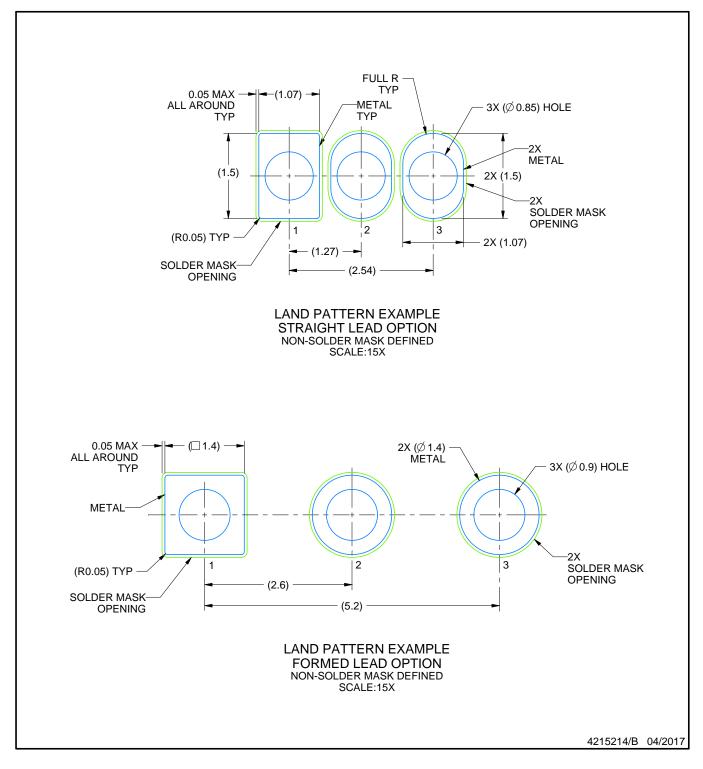


LP0003A

EXAMPLE BOARD LAYOUT

TO-92 - 5.34 mm max height

TO-92



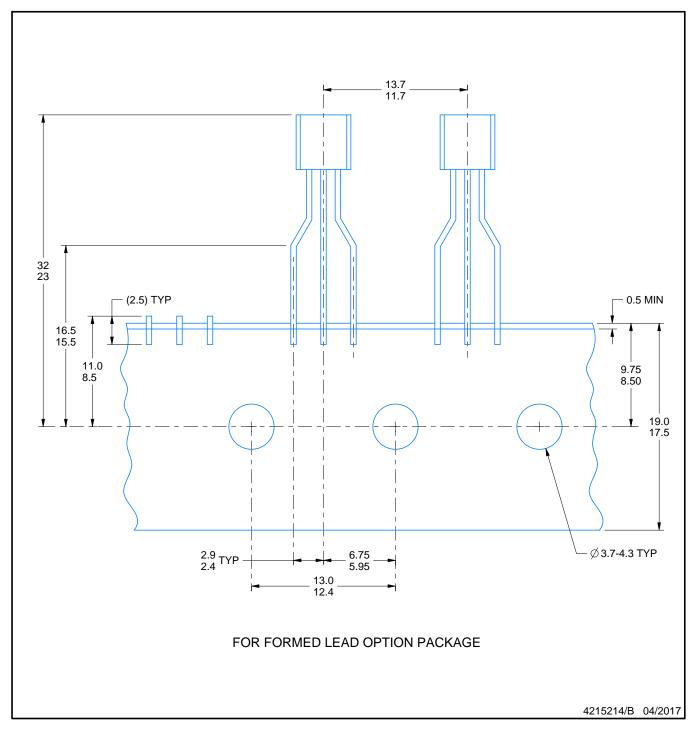


LP0003A

TAPE SPECIFICATIONS

TO-92 - 5.34 mm max height

TO-92





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